# **Excellent Integrated System Limited**

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

STMicroelectronics STTH102AY

For any questions, you can email us directly: <a href="mailto:sales@integrated-circuit.com">sales@integrated-circuit.com</a>





### **STTH102-Y**

## Automotive high efficiency ultrafast diode

#### **Features**

- Very low conduction losses
- Negligible switching losses
- Low forward and reverse recovery times
- High junction temperature
- ECOPACK®2 compliant component
- AEC-Q101 qualified

#### **Description**

The STTH102-Y, which is using ST's new 200 V planar technology, is specially suited for switching mode base drive and transistor circuits. The device is also intended for use as a free wheeling diode in power supplies and other power switching applications for automotive.

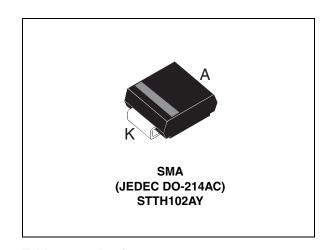


Table 1. Device summary

<b>,</b>				
Symbol	Value			
I <sub>F(AV)</sub>	1 A			
V <sub>RRM</sub>	200 V			
T <sub>j</sub> (max)	175 °C			
V <sub>F</sub> (max)	0.78 V			
t <sub>rr</sub> (max)	20 ns			

November 2011 Doc ID 17982 Rev 1 1/7



Characteristics STTH102-Y

### 1 Characteristics

Table 2. Absolute rating (limiting values)

Symbol	Parameter	Value	Unit	
$V_{RRM}$	Repetitive peak reverse voltage			V
I <sub>F(AV)</sub>	Average forward current	$T_L = 148  ^{\circ}\text{C}  \delta = 0.5$	1	Α
I <sub>FSM</sub>	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$		40	Α
T <sub>stg</sub>	Storage temperature range	-65 to + 175	°C	
T <sub>j</sub>	Operating junction temperature range			°C
dV/dt	Critical rate of rise of reverse voltage			V/µs

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit
R <sub>th(j-l)</sub>	Junction to lead	30	°C/W

**Table 4. Static Electrical Characteristics** 

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 25 °C	Vo - Voor			1	μA
'R`'	Theverse leakage current	T <sub>j</sub> = 125 °C	$V_R = V_{RRM}$		1	25	μΑ
V <sub>F</sub> <sup>(2)</sup>	Forward voltage drop	T <sub>i</sub> = 25 °C	$I_F = 700 \text{ mA}$			0.90	
		1 <sub>j</sub> = 25 C	I <sub>F</sub> = 1 A			0.97	V
		T <sub>j</sub> = 125 °C	I <sub>F</sub> = 1 A		0.68	0.78	

<sup>1.</sup> Pulse test:  $t_p = 5 \text{ ms}$ ,  $\delta < 2\%$ 

To evaluate the conduction losses use the following equation:  $P = 0.65 \times I_{F(AV)} + 0.130 I_{F^2(RMS)}$ 

Table 5. Dynamic electrical characteristics

	zynamie electrical charactericales						
Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
t <sub>rr</sub>	Reverse recovery time	T <sub>j</sub> = 25 °C	$I_F = 0.5 \text{ A } I_{rr} = 0.25 \text{ A}$ $I_R = 1 \text{ A}$		12	20	ns
t <sub>fr</sub>	Forward recovery time	T <sub>j</sub> = 25 °C	$I_F = 1 \text{ A}  dI_F/dt = 50 \text{ A/ms}$ $V_{FR} = 1.1 \text{ x } V_F \text{max}$		50		ns
V <sub>FP</sub>	Forward recovery voltage	T <sub>j</sub> = 25 °C	$I_F = 1 A dI_F/dt = 50 A/ms$		1.8		V

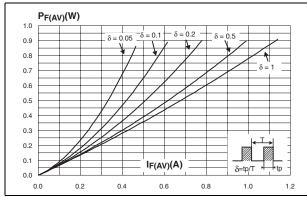
2/7 Doc ID 17982 Rev 1

<sup>2.</sup> Pulse test:  $t_p$  = 380  $\mu$ s,  $\delta$  < 2%



STTH102-Y Characteristics

Figure 1. Average forward power dissipation Figure 2. Average forward current versus versus average forward current ambient temperature ( $\delta = 0.5$ )



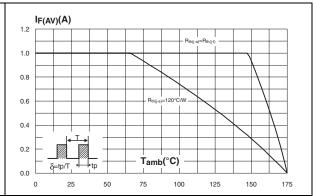
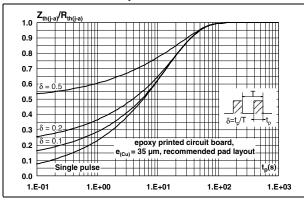


Figure 3. Relative variation of thermal impedance junction to ambient versus pulse duration

Figure 4. Forward voltage drop versus forward current



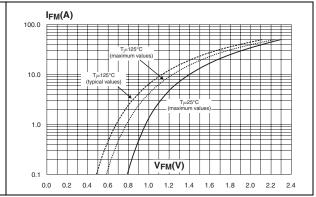
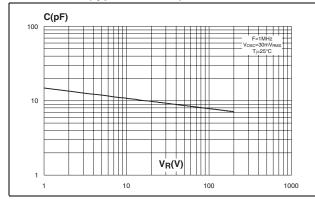
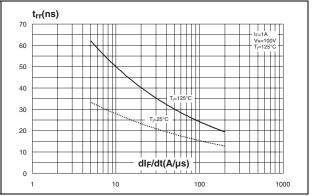


Figure 5. Junction capacitance versus reverse voltage applied (typical values)

Figure 6. Reverse recovery time versus  $dI_F/dt$  (90% confidence)

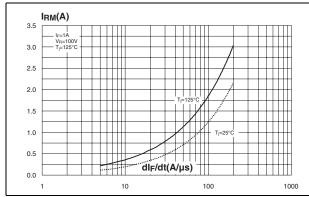






Characteristics STTH102-Y

Figure 7. Peak recovery current versus  $dI_F/dt$  Figure 8. Reverse recovery charges versus  $dI_F/dt$  (90% confidence)



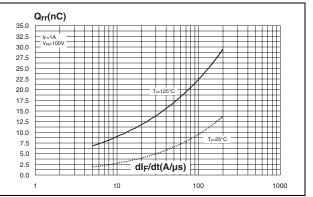
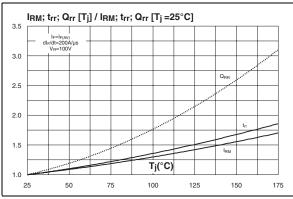
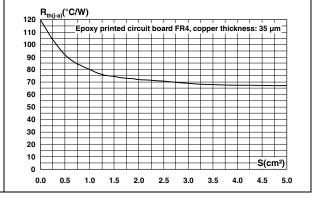


Figure 9. Relative variations of dynamic parameters versus junction temperature

Figure 10. Thermal resistance junction to ambient versus copper surface under each lead





4/7 Doc ID 17982 Rev 1



STTH102-Y Package information

### 2 Package information

- Epoxy meets UL94 V0
- Lead-free packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Table 6. SMA dimensions

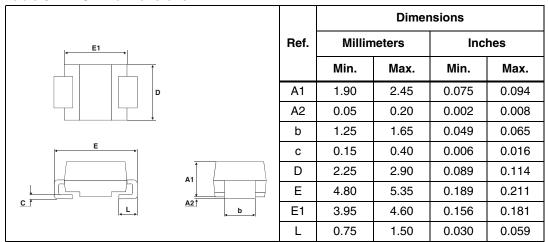
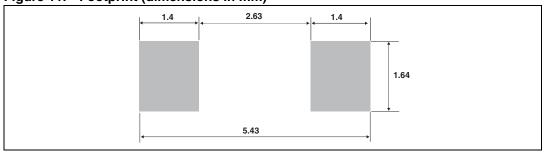


Figure 11. Footprint (dimensions in mm)





**Ordering information** 

STTH102-Y

# 3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH102AY	U12Y	SMA	0.068 g	5000	Tape and reel

## 4 Revision history

Table 8. Revision history

Date	Revision	Changes
07-Nov-2011	1	Initial release.

6/7 Doc ID 17982 Rev 1



## Distributor of STMicroelectronics: Excellent Integrated System Limited

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

Datasheet of STTH102AY - DIODE GEN PURP 200V 1A SMA

#### STTH102-Y

#### Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY TWO AUTHORIZED ST REPRESENTATIVES, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2011 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

